TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

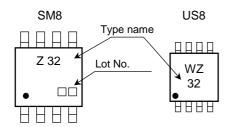
TC7WZ32FU,TC7WZ32FK

2 Input or Gate

Features

- High output drive: ±24 mA (min) @V_{CC} = 3 V
- Super high speed operation: $t_{pd} 2.4 \text{ ns} (typ.) @V_{CC} = 5 \text{ V}, 50 \text{ pF}$
- Operation voltage range: V_{CC} (opr) = 1.65~5.5 V
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (JEITA)
 - ± 2000 V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

Marking



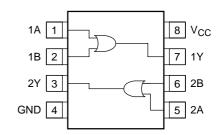
Maximum Ratings (Ta = 25°C)

TC7WZ32FU	~
	\rightarrow
d A	TOTAT
	LHHH
Ч	COB .
	8-P-0.65
TC7WZ32FK	
	TITAL
	RACION
SSOP8	-P-0.50A
Weight	

SSOP8-P-0.65 SSOP8-P-0.50A

: 0.02 g (typ.) : 0.01 g (typ.)

Pin Assignment (top view)

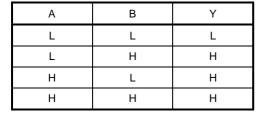


Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~6	V	
DC input voltage	V _{IN}	-0.5~6	V	
DC output voltage	V _{OUT}	-0.5~6	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	I _{OK}	-20	mA	
DC output current	IOUT	±50	mA	
DC V _{CC} /ground current	ICC	±50	mA	
Power dissipation	PD	300 (SM8) 200 (US8)	mW	
Storage temperature	T _{stg}	-65~150	°C	
Lead temperature (10s)	ΤL	260	°C	

TOSHIBA

Truth Table

Logic Diagram





Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	Vcc	1.65~5.5	V	
Supply voltage	VCC	1.5~5.5 (Note 1)		
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~5.5 (Note 2)	v	
	V001	0~V _{CC} (Note 3)		
Operating temperature	T _{opr}	-40~85	°C	
		0~20 (V _{CC} = 1.8 V \pm 0.15 V, 2.5 V \pm 0.2 V)	ns/V	
Input rise and fall time	d _t /d _v	0~10 (V_{CC} = 3.3 V \pm 0.3 V)		
		0~5 (V _{CC} = 5.5 V \pm 0.5 V)		

Note 1: Data retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or low state

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Symbol	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
				V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
High level		Mar			1.65~ 1.95	$\begin{array}{c} 0.75 \\ \times \ V_{CC} \end{array}$	_	_	$\begin{array}{c} 0.75 \\ \times \ V_{CC} \end{array}$	—	V
Input voltage	Figitievei	gh level V _{IH}		—		$0.7 \\ \times V_{CC}$	_	_	$0.7 \\ \times V_{CC}$	_	
			_		1.65~ 1.95	_		$\begin{array}{c} 0.25 \\ \times \ V_{CC} \end{array}$	_	$0.25 \\ \times V_{CC}$	V
	Low level	VIL			2.3~5.5	_		$0.3 \\ \times V_{CC}$	_	$0.3 \\ \times \ V_{CC}$	
					1.65	1.55	1.65	_	1.55	—	
		V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = −100 μA	2.3	2.2	2.3		2.2	—	
				10H = -100 μΑ	3.0	2.9	3.0		2.9	—	
					4.5	4.4	4.5		4.4	—	
	High level			$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52		1.29	—	
				I _{OH} = -8 mA	2.3	1.9	2.15		1.9	—	
				I _{OH} = -16 mA	3.0	2.4	2.8	_	2.4	—	
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68		2.3	—	
Output				I _{OH} = -32 mA	4.5	3.8	4.2	_	3.8	_	
voltage	Low level	V _{OL}	V _{IN} = V _{IL}	I _{OL} = 100 μA	1.8		0	0.1		0.1	v
					2.3		0	0.1		0.1	
					3.0	—	0	0.1		0.1	
					4.5		0	0.1	_	0.1	
				$I_{OL} = 4 \text{ mA}$	1.65	—	0.08	0.24	_	0.24	
				I _{OL} = 8 mA	2.3		0.1	0.3		0.3	
				I _{OL} = 16 mA	3.0		0.15	0.4		0.4	
				I _{OL} = 24 mA	3.0	—	0.22	0.55		0.55	
				I _{OL} = 32 mA	4.5		0.22	0.55	_	0.55	
	Input leakage current I_{IN} $V_{IN} = 5.5$ V or GND		0~5.5		_	±1		±10	μA		
Power off lea	kage current	IOFF	$V_{\text{IN}} \text{ or } V_{\text{OL}}$		0.0			1		10	μA
Quiescent supply current		ICC	$V_{IN} = 5.5 \text{ V or GND}$		1.65~5.5	—	—	1	_	10	μA

AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	^t pLH t _{pHL}	C_L = 15 pF, R_L = 1 M Ω	1.8 ± 0.15	2.0	5.8	10.5	2.0	11.0	ns
			$\textbf{2.5}\pm\textbf{0.2}$	1.0	3.5	5.8	1.0	6.2	
			$\textbf{3.3}\pm\textbf{0.3}$	0.8	2.6	3.9	0.8	4.3	
			5.0 ± 0.5	0.5	2.6	3.1	0.5	3.3	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$\textbf{3.3}\pm\textbf{0.3}$	1.2	3.2	4.8	1.2	5.2	
			5.0 ± 0.5	0.8	2.4	3.7	0.8	4.0	
Input capacitance	C _{IN}	—	0~5.5	_	3.0	_	_	—	pF
Power dissipation capacitance	C _{PD}	(Note)	3.3	_	20		_	_	pF
		(Note)	5.5		26				

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

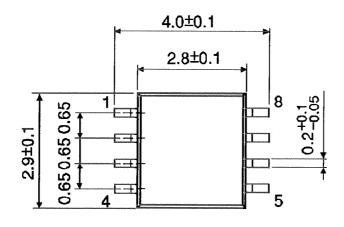
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

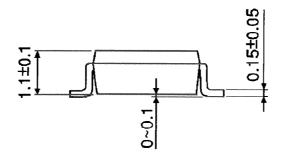
TOSHIBA

Package Dimensions

SSOP8-P-0.65

Unit : mm





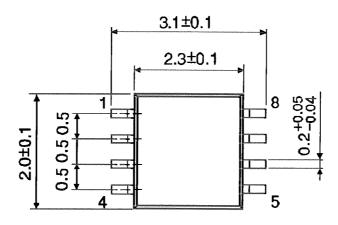
Weight: 0.02 g (typ.)

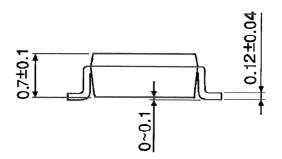
TOSHIBA

Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

RESTRICTIONS ON PRODUCT USE

Handbook" etc..

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.